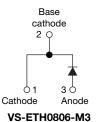
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Hyperfast Rectifier, 8 A FRED Pt[®]

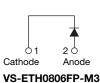


2L TO-220AC





2L TO-220 FULL-PAK



VS-ETI

PRODUCT SUMMARY					
Package	2L TO-220AC, 2L TO-220FP				
I _{F(AV)}	8 A				
V _R	600 V				
V _F at I _F	1.3 V				
t _{rr} (typ.)	16 ns				
T _J max.	175 °C				
Diode variation	Single die				

FEATURES

- Hyperfast soft recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- True 2 pin package
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		600	V		
Average rectified forward current in		T _C = 146 °C	8			
DC FULL-PAK	K I _{F(AV)}	T _C = 114 °C	0	A		
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	80			
Repetitive peak surge current	1	T _C = 137 °C				
Square wave 20 kHz duty cycle (50 %) FULL-PAK	IFRM	T _C = 96 °C	10	A		
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	YMBOLTEST CONDITIONSMIN.TYP.MAX.					
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward voltage	V _F	I _F = 8 A	-	2.0	2.65	V	
		I _F = 8 A, T _J = 150 °C	-	1.3	1.85		
		$V_{R} = V_{R}$ rated	-	0.02	12		
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	15	100	μA	
Junction capacitance	CT	C _T V _R = 600 V		6	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	

Revision: 15-Jun-15

Document Number: 93515

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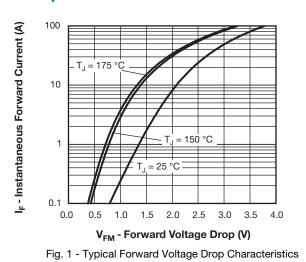


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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100$	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		16	23	
Powerse receiver time	+	$I_F = 8 \text{ A}, \ dI_F/dt = 100$	$I_F = 8 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		20	28	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	21	-	ns
		T _J = 125 °C	I _F = 8 A dI _F /dt = 200 A/μs V _R = 390 V	-	39	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	3	-	A
Peak recovery current		T _J = 125 °C		-	5	-	
	Q _{rr}	T _J = 25 °C		-	36	-	nC
Reverse recovery charge		T _J = 125 °C		-	108	-	nc
Reverse recovery time	t _{rr}		I _F = 8 A	-	30	-	ns
Peak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 600 A/µs	-	13	-	А
Reverse recovery charge	Q _{rr}		V _R = 390 V	-	205	-	nC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance,	D		-	2.0	2.6		
junction to case FULL-PAK	R _{thJC}		-	4.6	5.5		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-		
			-	2	-	g	
Weight			-	0.07	-	oz.	
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)	
Marking davias		Case style 2L TO-220AC	ETH0806				
Marking device		Case style 2L TO-220 FULL-PAK		ETH0	806FP		





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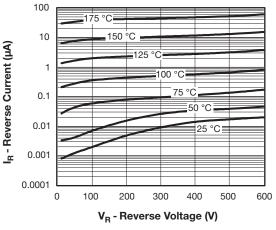
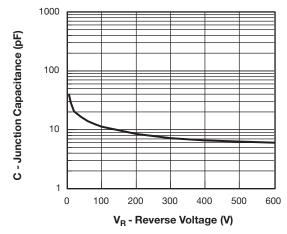
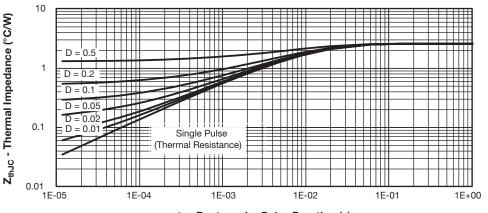


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage







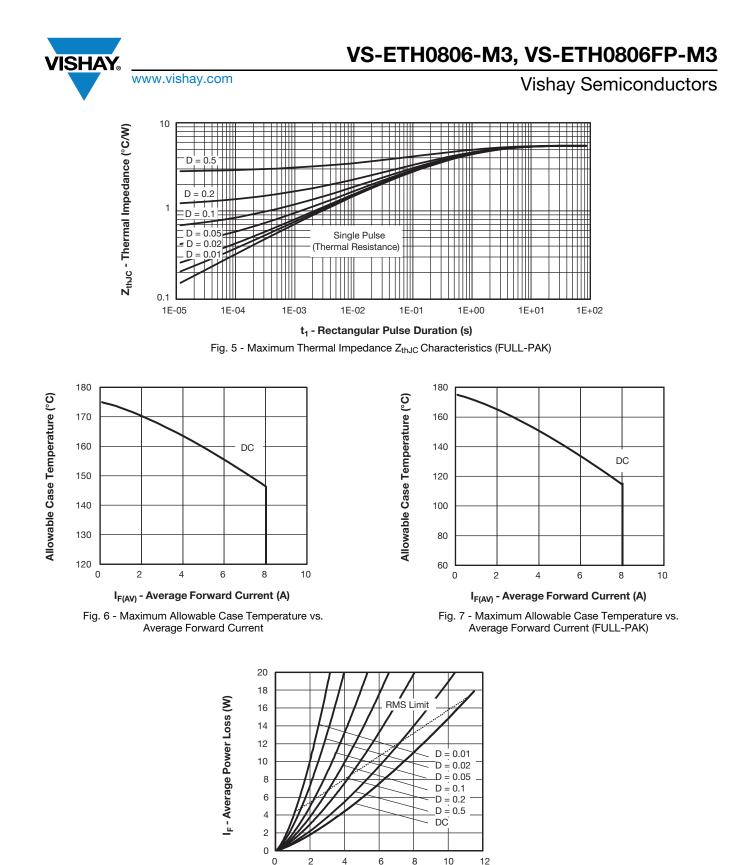
t₁ - Rectangular Pulse Duration (s)

Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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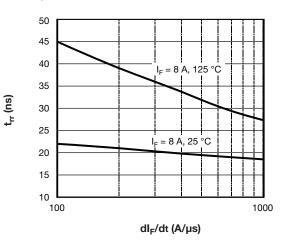
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I_{F(AV)} - Average Forward Current (A) Fig. 8 - Forward Power Loss Characteristics

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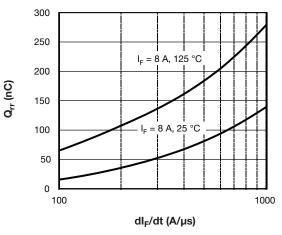
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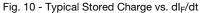


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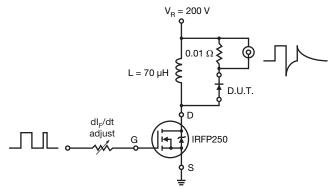


Fig. 11 - Reverse Recovery Parameter Test Circuit

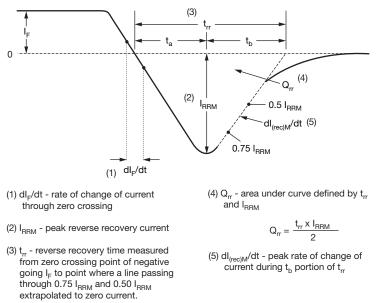
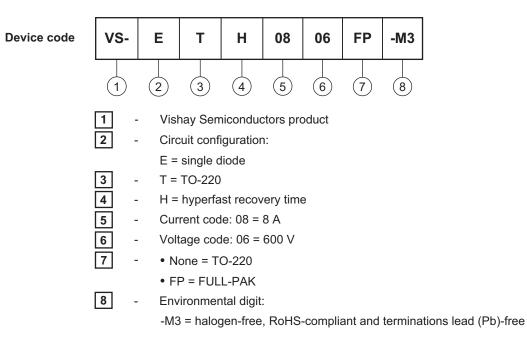


Fig. 12 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-ETH0806-M3	50	1000	Antistatic plastic tube			
VS-ETH0806FP-M3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	2L TO-220AC	www.vishay.com/doc?95259			
Dimensions	2L TO-220 FULL-PAK	www.vishay.com/doc?95260			
Part marking information	2L TO-220AC	www.vishay.com/doc?95391			
	2L TO-220 FULL-PAK	www.vishay.com/doc?95392			

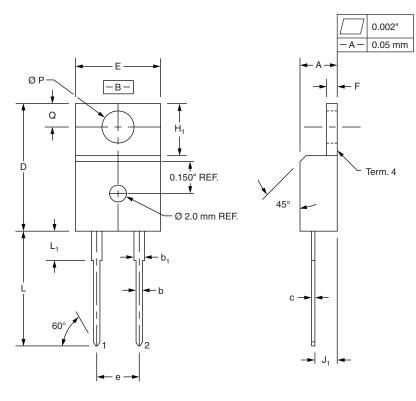




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True 2 Pin TO-220

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INCH	IES
STMBOL	MIN.	MAX.	MIN.	MAX.
А	4.32	4.57	0.170	0.180
b	0.71	0.91	0.028	0.036
b ₁	1.15	1.39	0.045	0.055
с	0.36	0.53	0.014	0.021
D	14.99	15.49	0.590	0.610
E	10.04	10.41	0.395	0.410
e	5.08	BSC	0.200	BSC
F	1.22	1.37	0.048	0.054
H ₁	5.97	6.47	0.235	0.255
J ₁	2.54	2.79	0.100	0.110
L	13.47	13.97	0.530	0.550
L ₁ ⁽¹⁾	3.31	3.81	0.130	0.150
ØP	3.79	3.88	0.149	0.153
Q	2.60	2.84	0.102	0.112

Notes

 $^{\left(1\right)}$ Lead dimension and finish uncontrolled in L_{1}

• These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87

Controling dimension: Inch

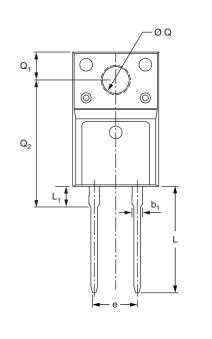


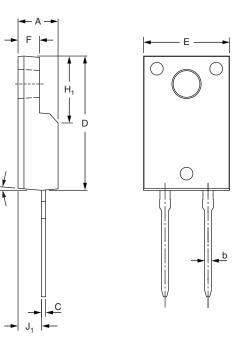


True 2 Pin TO-220 FULL-PAK

θ

DIMENSIONS in millimeters and inches





SYMBOL	MILLIN	METERS	INC	HES	
STMBUL	MIN.	MAX.	MIN.	MAX.	
A	4.53	4.93	0.178	0.194	
b	0.71	0.91	0.028	0.036	
b ₁	1.15	1.39	0.045	0.055	
С	0.36	0.53	0.014	0.021	
D	15.67	16.07	0.617	0.633	
E	9.96	10.36	0.392	0.408	
e	5.08	5.08 typical 0.200		typical	
F	2.34	2.74	0.092	0.107	
H ₁	6.50	6.90	0.256	0.272	
J ₁	2.56	2.96	0.101	0.117	
L	12.78	13.18	0.503	0.519	
L ₁	2.23	2.63	0.088	0.104	
ØQ	2.98	3.38	0.117	0.133	
Q ₁	3.10	3.50	0.122	0.138	
Q ₂	14.80	15.20	0.583	0.598	
θ	0°	5°	0°	5°	



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